

5A Lead Type Low Barrier Diode

■ Features

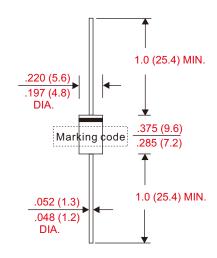
- Axial lead type devices for through hole design.
- Low forward voltage drop.
- Excellent high temperature stability.
- · Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSRL560G-A.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case: Molded plastic, DO-201AD / DO-27
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity: Color band denotes cathode end
- Weight: Approximated 1.10 gram

■ Outline

DO-27(DO-201AD)



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CSRL560-A	LINUT	
Marking code			CSRL560	UNIT	
Peak repetitive reverse voltage		V _{RRM}			
Working peak reverse voltage		V _{RWM}	60	V	
DC blocking voltage		V _{RM}			
Forward rectified current		Io	5	Α	
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	150	А	
Peak repetitive reverse surge current	2us - 1kHz	I _{RRM}	2	А	
Thermal resistance	Junction to case	R _{eJC}	20	°C/W	
Operating and Storage temperature		T _J , T _{stg}	-65 ~ +150	°C	

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
I Forward voltage drop	$I_{F} = 5A, T_{J} = 25^{\circ}C$	V _F			520	mV
	$I_F = 5A, T_J = 125^{\circ}C$				470	
I Reverse current	$V_R = V_{RRM} T_J = 25^{\circ}C$	- I _R			0.5	mA
	$V_R = V_{RRM} T_J = 125^{\circ}C$				100	

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■ Rating and characteristic curves

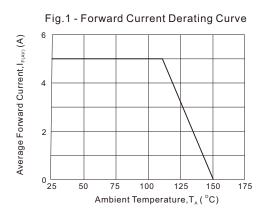


Fig. 2 - Instantaneous Forward Characteristics 100 Instantaneous Forward Current, I_F (A) T_A=150°C 10 T_A=125°C . -75°C 0.1 T_A=50°C T_A=25°C 0.01 0.4 0.5 0.6 0.7 0.8 0.2 0.3 Instantaneous Forward Voltage, V_F (Volts)

100 Instantaneous Reverse Current, $I_{\rm R}$ (mA) T_A=150°C 10 T_A=125°C T_A=100°C T_A=75°C-0.1 T_A=50°C T_A=25°C 0.01 10 50 60 Reverse Voltage, V_R (V)

Fig. 3 - Reverse Characteristics

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http://www.citcorp.com.tw/

Tel:886-3-5600628

Fax:886-3-5600636

Add:Rm. 3, 2F., No.32, Taiyuan St., Zhubei City, Hsinchu County 302, Taiwan (R.O.C.)

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